

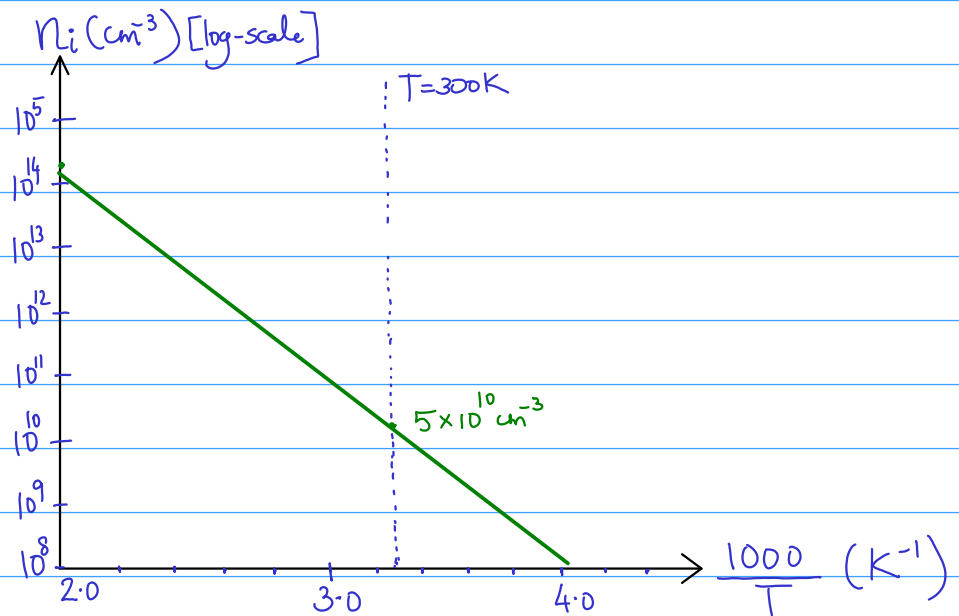
Assignment-03

[A] Semiconductors: Charge-Carrier density

Q1. A silicon sample is doped with 10^{17} As atoms cm^{-3} . What is the equilibrium hole density at 300K? Where is E_F relative to E_c ? [Assume: $n_i = 1.5 \times 10^{10} \text{ cm}^{-3}$ and $N_c = 1 \times 10^{19} \text{ cm}^{-3}$]

Q2. A silicon bar 0.1 cm long and $100 \mu\text{m}^2$ in cross-sectional area is doped with 10^{17} cm^{-3} phosphorus atoms. Calculate the electron density at 300K. Find the current at 300K with 10V applied. [Assume: Mobility of electrons at 300K = $100 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$]

Q3. The following figure shows variation of intrinsic charge-carrier density n_i with the temperature. Use the data to estimate the band-gap of the semiconductor.



Q4. Justify why holes are found at the top of the valance band, whereas electrons are found at the bottom of the conduction band.

Q5. A silicon sample is doped with $6 \times 10^{15} \text{ cm}^{-3}$ donor atoms from one end and with $2 \times 10^{15} \text{ cm}^{-3}$ acceptor atoms from other end. Find the position of Fermi energy level w.r.t. corresponding band edge (E_c or E_v) at 300K.

[Assume: $N_c = N_v = 1 \times 10^{19} \text{ cm}^{-3}$ at 300K]

[B] p-n Homojunction Diodes: Circuit Problems

1. An a.c. voltage of peak value 20 V is connected in series with a silicon diode and load resistance of $500\ \Omega$. If the forward resistance of the diode is $10\ \Omega$, find : (i) peak current through diode (ii) peak output voltage across the load. What will be these values if the diode is assumed to be ideal ?
2. Find the current through the diode in the circuit shown in Fig. 1. Assume the diode to be ideal.

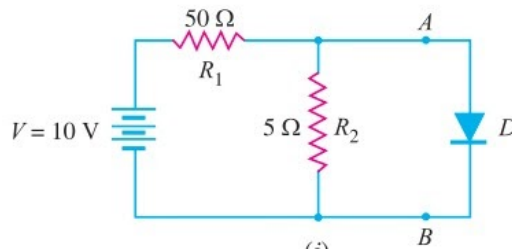


Fig. 1

3. Determine the current I in the circuit shown in Fig. 2. Assume the diodes to be of silicon (turn-On voltage = 0.7V) and forward resistance of diodes to be zero.

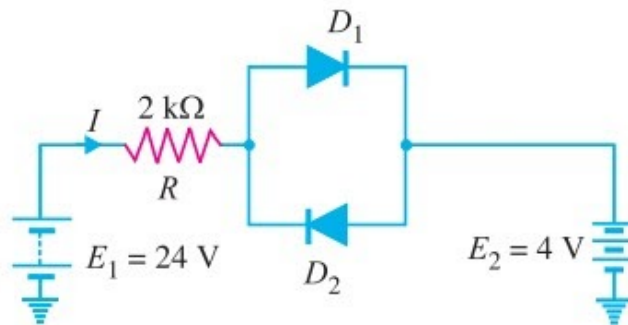


Fig. 2

4. A crystal diode having internal resistance $r_f = 20\ \Omega$ is used for half-wave rectification. If the applied a.c. voltage is $v(t) = 50 \sin(\omega t)$ and load resistance $R_L = 800\ \Omega$, find: (i) I_m , I_{dc} , I_{rms} (ii) a.c. power input and d.c. power output (iii) d.c. output voltage (iv) efficiency of rectification.
5. A half-wave rectifier is used to supply 50V d.c. to a resistive load of $800\ \Omega$. The diode has a resistance of $25\ \Omega$. Calculate a.c. voltage required.
6. Consider a half-wave rectifier designed connecting a diode and a load resistance across the secondary winding of a step-down transformer. Let $v_s(t) = V_m \sin \omega t$ be the alternating voltage that appears across the secondary winding. Let r_f and R_L be the diode resistance and load resistance, respectively. Show that the maximum rectifier efficiency $\eta_{max} = 40.6\%$. What do you expect if you design a full wave rectifier?

7. A full-wave rectifier uses two diodes, the internal resistance of each diode may be assumed constant at $20\ \Omega$. The transformer r.m.s. secondary voltage from centre tap to each end of secondary is 50 V and load resistance is $980\ \Omega$. Find : (i) the average load current (ii) the r.m.s. value of load current.
8. For the circuit shown in Fig. 3, find the output d.c. voltage.

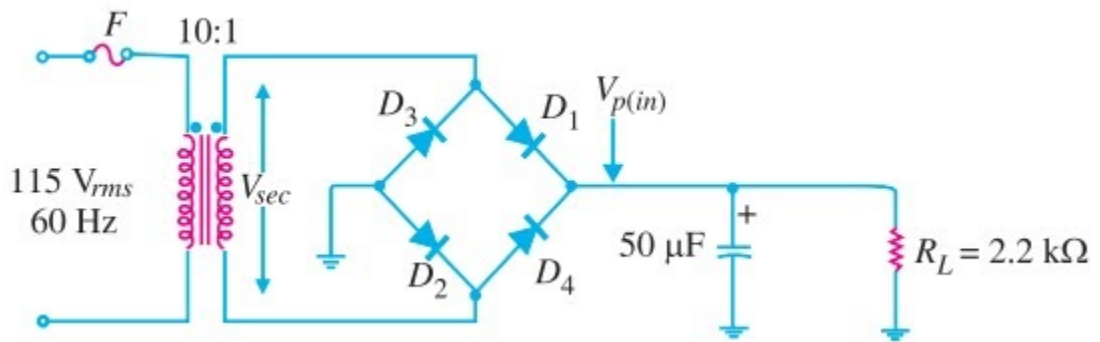


Fig. 3

9. The zener diode shown in Fig. 4 has $V_Z = 18\text{ V}$. The voltage across the load stays at 18 V as long as I_Z is maintained between 200 mA and 2 A . Find the value of series resistance R so that E_O remains 18 V while input voltage V_i is free to vary between 22 V to 28 V .

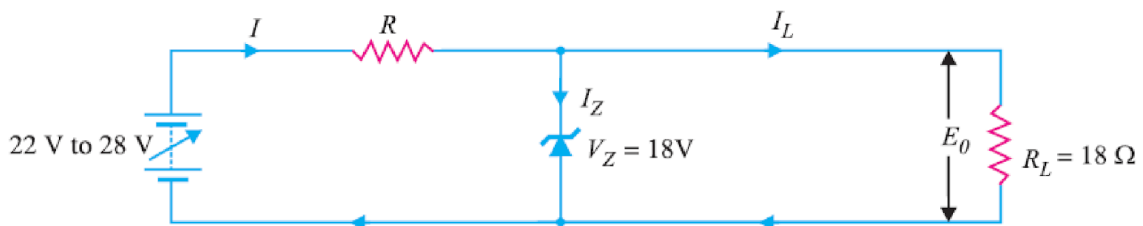


Fig. 4

10. A 10-V zener diode is used to regulate the voltage across a variable load resistor [see Fig. 5]. The input voltage varies between 13 V and 16 V and the load current varies between 10 mA and 85 mA . The minimum zener current is 15 mA . Calculate the value of series resistance R .

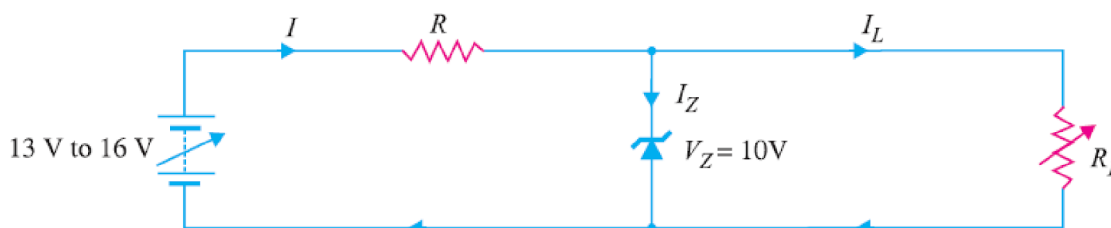


Fig. 5

11. The circuit of Fig. 6 uses two zener diodes, each rated at 15 V , 200 mA . If the circuit is connected to a 45-volt unregulated supply, determine : (i) The regulated output voltage (ii) The value of series resistance R .

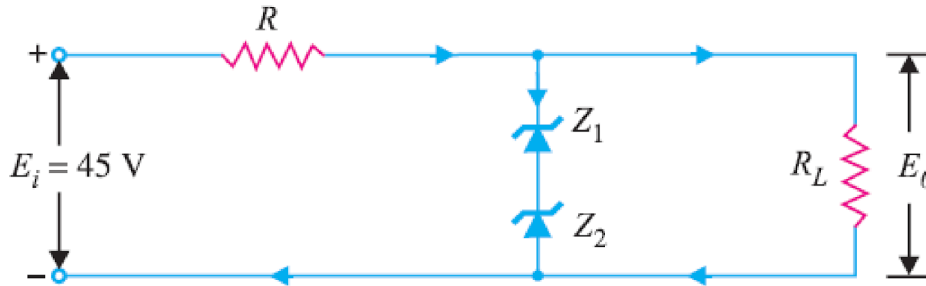


Fig. 6

12. What value of series resistance R is required when three 10-watt, 10-volt, 1000 mA zener diodes are connected in series to obtain a 30-volt regulated output from a 45 volt d.c. power source? [See Fig.7]

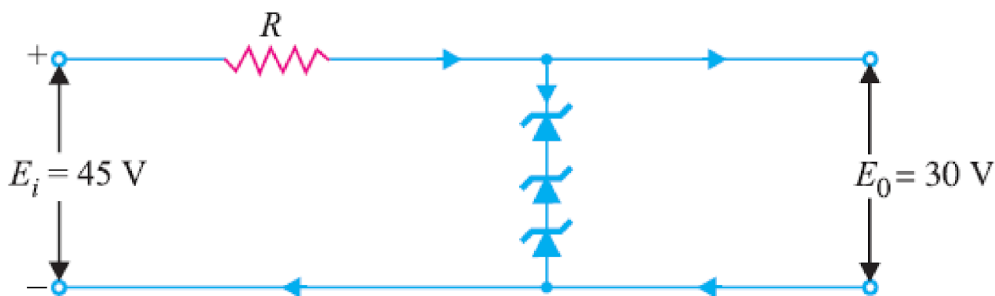


Fig. 7

13. Over what range of input voltage will the zener circuit shown in Fig. 8 maintain 30 V across $2000\ \Omega$ load, assuming that series resistance $R = 200\ \Omega$ and zener current rating is 25 mA?

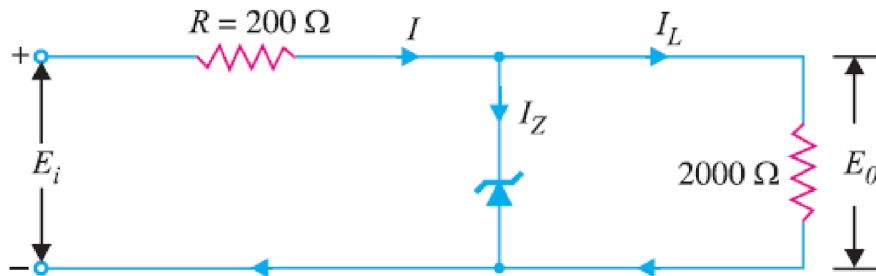


Fig. 8

14. In the circuit shown in Fig. 9, the voltage across the load is to be maintained at 12 V as load current varies from 0 to 200 mA. Design the regulator. Also find the maximum wattage rating of the zener diode.

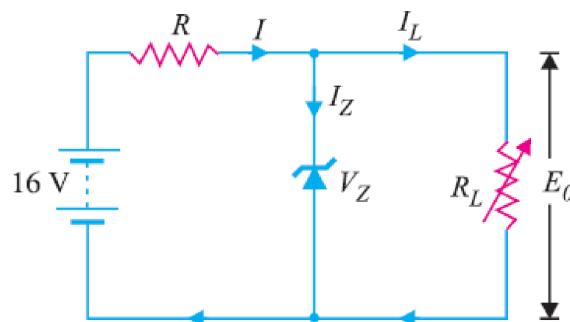


Fig. 9

15. In the circuit shown in Fig. 10, determine the range of R_L that will result in a constant voltage of 10 V across R_L .

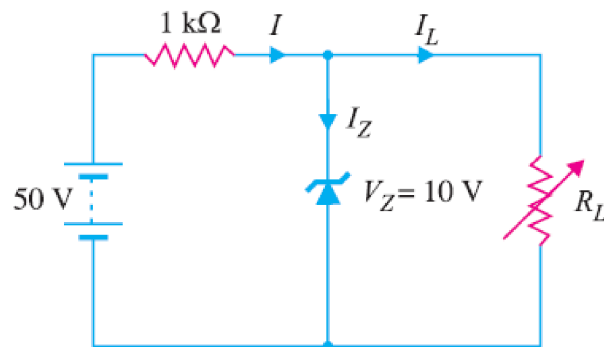


Fig. 10